

MC74LCX07

Low-Voltage CMOS Hex Buffer with Open Drain Outputs

With 5 V-Tolerant Inputs

The MC74LCX07 is a high performance hex buffer operating from a 2.3 to 3.6 V supply. High impedance TTL compatible inputs significantly reduce current loading to input drivers. These LCX devices have open drain outputs which provide the ability to set output levels, or do active-HIGH AND or active-LOW OR functions. A V_I specification of 5.5 V allows MC74LCX07 inputs to be safely driven from 5.0 V devices.

Features

- Designed for 2.3 to 3.6 V V_{CC} Operation
- 5.0 V Tolerant Inputs/Outputs
- LVTTTL Compatible
- LVC MOS Compatible
- 24 mA Output Sink Capability
- Near Zero Static Supply Current (10 μ A) Substantially Reduces System Power Requirements
- Latchup Performance Exceeds 500 mA
- Wired-OR, Wired-AND
- Output Level Can Be Set Externally Without Affecting Speed of Device
- ESD Performance: Human Body Model >1500 V;
Machine Model >200 V
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

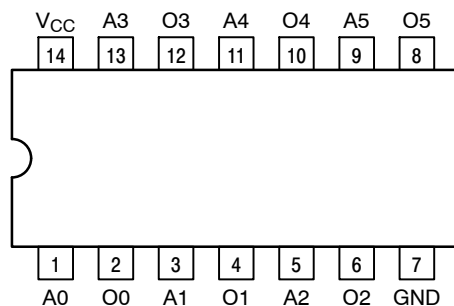


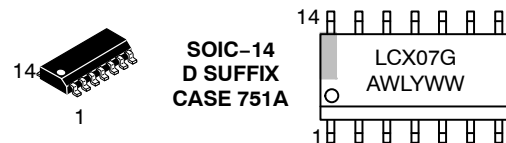
Figure 1. Pinout: 14-Lead (Top View)



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MARKING DIAGRAMS



- A = Assembly Location
 - L, WL = Wafer Lot
 - Y, YY = Year
 - W, WW = Work Week
 - G = Pb-Free Package
 - = Pb-Free Package
- (Note: Microdot may be in either location)

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 2 of this data sheet.

MC74LCX07

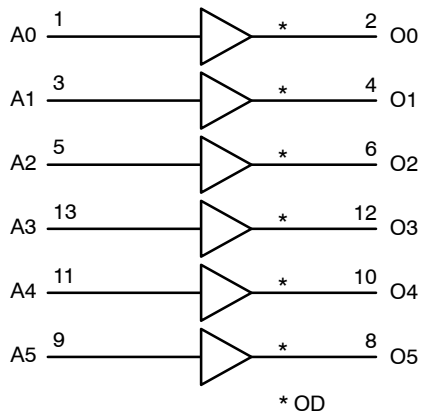


Figure 2. Logic Diagram

PIN NAMES

| Pins | Function |
|------|-------------|
| An | Data Inputs |
| On | Outputs |

TRUTH TABLE

| An | On |
|----|----|
| L | L |
| H | Z |

MAXIMUM RATINGS

| Symbol | Parameter | Value | Condition | Unit |
|-----------|----------------------------------|---------------------------|--------------------------------------|-------------|
| V_{CC} | DC Supply Voltage | -0.5 to +7.0 | | V |
| V_I | DC Input Voltage | $-0.5 \leq V_I \leq +7.0$ | | V |
| V_O | DC Output Voltage | $-0.5 \leq V_O \leq +7.0$ | Output in HIGH or LOW State (Note 1) | V |
| I_{IK} | DC Input Diode Current | -50 | $V_I < GND$ | mA |
| I_{OK} | DC Output Diode Current | -50 | $V_O < GND$ | mA |
| | | +50 | $V_O > V_{CC}$ | mA |
| I_O | DC Output/Sink Current | +50 | | mA |
| I_{CC} | DC Supply Current Per Supply Pin | ± 100 | | mA |
| I_{GND} | DC Ground Current Per Ground Pin | ± 100 | | mA |
| T_{STG} | Storage Temperature Range | -65 to +150 | | $^{\circ}C$ |
| MSL | Moisture Sensitivity | | Level 1 | |

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

1. I_O absolute maximum rating must be observed.

ORDERING INFORMATION

| Device | Package | Shipping [†] |
|----------------|-----------------------|-----------------------|
| MC74LCX07DG | SOIC-14 (Pb-Free) | 55 Units / Rail |
| MC74LCX07DR2G | SOIC-14 (Pb-Free) | 2500 Tape & Reel |
| MC74LCX07DTG | TSSOP-14 (Pb-Free) | 96 Units / Rail |
| MC74LCX07DTR2G | TSSOP-14 (Pb-Free) | 2500 Tape & Reel |

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

MC74LCX07

RECOMMENDED OPERATING CONDITIONS

| Symbol | Parameter | Min | Typ | Max | Unit |
|-----------------|--|------------|------------|------------------|------|
| V _{CC} | Supply Voltage Operating Data Retention Only | 2.0 1.5 | 2.3 to 3.3 | 5.5 5.5 | V |
| V _I | Input Voltage | 0 | | 5.5 | V |
| V _O | Output Voltage (HIGH or LOW State) | 0 | | 5.5 | V |
| I _{OH} | HIGH Level Output Current V _{CC} = 3.0 V–3.6 V V _{CC} = 2.7 V–3.0 V V _{CC} = 2.3 V–2.7 V | | | –24 –12 –8 | mA |
| I _{OL} | LOW Level Output Current V _{CC} = 3.0 V–3.6 V V _{CC} = 2.7 V–3.0 V V _{CC} = 2.3 V–2.7 V | | | +24 +12 +8 | mA |
| T _A | Operating Free–Air Temperature | –40 | | +85 | °C |
| Δt/ΔV | Input Transition Rise or Fall Rate, V _{IN} from 0.8 V to 2.0 V, V _{CC} = 3.0 V | 0 | | 10 | ns/V |

DC ELECTRICAL CHARACTERISTICS

| Symbol | Characteristic | Condition | T _A = –40°C to +85°C | | Unit |
|------------------|---------------------------------------|--|---------------------------------|------|------|
| | | | Min | Max | |
| V _{IH} | HIGH Level Input Voltage (Note 2) | 2.3 V ≤ V _{CC} ≤ 2.7 V | 1.7 | | V |
| | | 2.7 V ≤ V _{CC} ≤ 3.6 V | 2.0 | | |
| | | 4.5 V ≤ V _{CC} ≤ 5.25 V | 3.125 | | |
| V _{IL} | LOW Level Input Voltage (Note 2) | 2.3 V ≤ V _{CC} ≤ 2.7 V | | 0.7 | V |
| | | 2.7 V ≤ V _{CC} ≤ 3.6 V | | 0.8 | |
| | | 4.5 V ≤ V _{CC} ≤ 5.25 V | | 0.8 | |
| V _{OL} | LOW Level Output Voltage | 2.3 V ≤ V _{CC} ≤ 3.6 V; I _{OL} = 100 μA | | 0.2 | V |
| | | V _{CC} = 2.3 V; I _{OL} = 8 mA | | 0.3 | |
| | | V _{CC} = 2.7 V; I _{OL} = 12 mA | | 0.4 | |
| | | V _{CC} = 3.0 V; I _{OL} = 16 mA | | 0.4 | |
| | | V _{CC} = 3.0 V; I _{OL} = 24 mA | | 0.55 | |
| I _{OZ} | 3–State Output Current | V _{CC} = 3.6 V, V _{IN} = V _{IH} or V _{IL} , V _{OUT} = 0 to 5.5 V | | ± 5 | μA |
| I _{OFF} | Power Off Leakage Current | V _{CC} = 0, V _{IN} = 5.5 V or V _{OUT} = 5.5 V | | 10 | μA |
| I _{IN} | Input Leakage Current | V _{CC} = 3.6 V, V _{IN} = 5.5 V or GND | | ± 5 | μA |
| I _{CC} | Quiescent Supply Current | V _{CC} = 3.6 V, V _{IN} = 5.5 V or GND | | 10 | μA |
| ΔI _{CC} | Increase in I _{CC} per Input | 2.3 V ≤ V _{CC} ≤ 3.6 V | | 500 | μA |
| | | 4.5 V ≤ V _{CC} ≤ 5.5 V | | 1.0 | mA |
| | | V _{CC} = 5.25 V, one input at 3.125 V, other inputs at V _{CC} or GND | | 10 | mA |

2. These values of V_I are used to test DC electrical characteristics only.

AC ELECTRICAL CHARACTERISTICS

| Symbol | Parameter | Limits | | | | | | Unit |
|------------------|-------------------|---------------------------------|-----|-------------------------|-----|---------------------------------|-----|------|
| | | T _A = –40°C to +85°C | | | | | | |
| | | V _{CC} = 3.3 V ± 0.3 V | | V _{CC} = 2.7 V | | V _{CC} = 2.5 V ± 0.2 V | | |
| | | C _L = 50 pF | | C _L = 50 pF | | C _L = 30 pF | | |
| | | Min | Max | Min | Max | Min | Max | |
| t _{PLZ} | Propagation Delay | 0.5 | 3.0 | 0.8 | 3.7 | 0.8 | 3.8 | ns |
| t _{PZL} | Input to Output | 0.5 | 3.0 | 0.8 | 3.7 | 0.8 | 3.8 | ns |

MC74LCX07

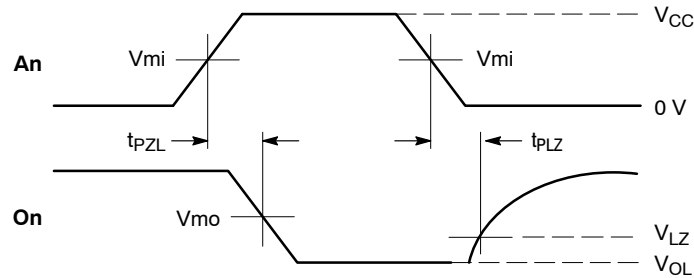
DYNAMIC SWITCHING CHARACTERISTICS

| Symbol | Characteristic | Condition | T _A = +25°C | | | Unit |
|------------------|-------------------------------------|--|------------------------|--------------|-----|------|
| | | | Min | Typ | Max | |
| V _{OLP} | Dynamic LOW Peak Voltage (Note 3) | V _{CC} = 3.3 V, C _L = 50 pF, V _{IH} = 3.3 V, V _{IL} = 0 V V _{CC} = 2.5 V, C _L = 30 pF, V _{IH} = 2.5 V, V _{IL} = 0 V | | 0.9 0.7 | | V |
| V _{OLV} | Dynamic LOW Valley Voltage (Note 3) | V _{CC} = 3.3 V, C _L = 50 pF, V _{IH} = 3.3 V, V _{IL} = 0 V V _{CC} = 2.5 V, C _L = 30 pF, V _{IH} = 2.5 V, V _{IL} = 0 V | | -0.8 -0.6 | | V |

3. Number of outputs defined as “n”. Measured with “n-1” outputs switching from HIGH-to-LOW or LOW-to-HIGH. The remaining output is measured in the LOW state.

CAPACITIVE CHARACTERISTICS

| Symbol | Parameter | Condition | Typical | Unit |
|------------------|-------------------------------|--|---------|------|
| C _{IN} | Input Capacitance | V _{CC} = 3.3 V, V _I = 0 V or V _{CC} | 7 | pF |
| C _{OUT} | Output Capacitance | V _{CC} = 3.3 V, V _I = 0 V or V _{CC} | 8 | pF |
| C _{PD} | Power Dissipation Capacitance | 10 MHz, V _{CC} = 3.3 V, V _I = 0 V or V _{CC} | 25 | pF |

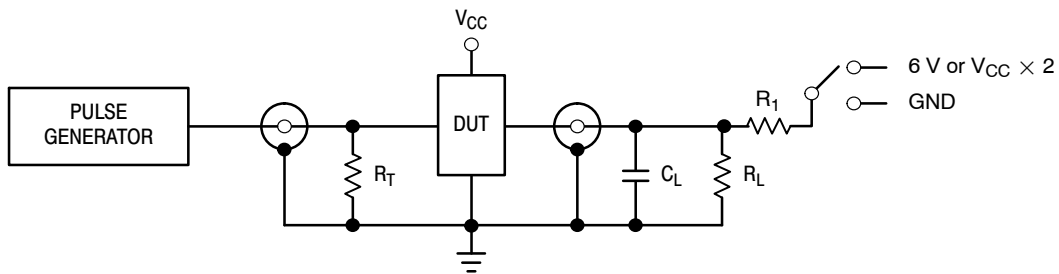


PROPAGATION DELAYS

$$t_R = t_F = 2.5 \text{ ns, } 10\% \text{ to } 90\%; f = 1\text{MHz}; t_W = 500 \text{ ns}$$

| Symbol | V _{CC} | | |
|-----------------|-------------------------|-------------------------|--------------------------|
| | 3.3 V ± 0.3 V | 2.7 V | 2.5 V ± 0.2 V |
| V _{mi} | 1.5 V | 1.5 V | V _{CC} /2 |
| V _{mo} | 1.5 V | 1.5 V | V _{CC} /2 |
| V _{LZ} | V _{OL} + 0.3 V | V _{OL} + 0.3 V | V _{OL} + 0.15 V |

Figure 3. AC Waveforms

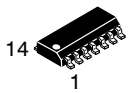


| TEST | SWITCH |
|--|--------|
| t _{PZL} , t _{PLZ} | 6 V |
| Open Collector/Drain t _{PLH} and t _{PHL} | 6 V |
| t _{PZH} , t _{PHZ} | GND |

C_L = 50 pF at V_{CC} = 3.3 ± 0.3 V or equivalent (includes jig and probe capacitance)
 C_L = 30 pF at V_{CC} = 2.5 ± 0.2 V or equivalent (includes jig and probe capacitance)
 R_L = R₁ = 500 Ω or equivalent
 R_T = Z_{OUT} of pulse generator (typically 50 Ω)

Figure 4. Test Circuit

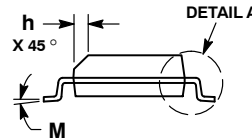
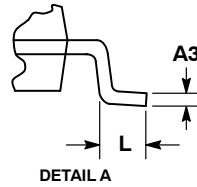
MECHANICAL CASE OUTLINE PACKAGE DIMENSIONS



SCALE 1:1

SOIC-14 NB
CASE 751A-03
ISSUE L

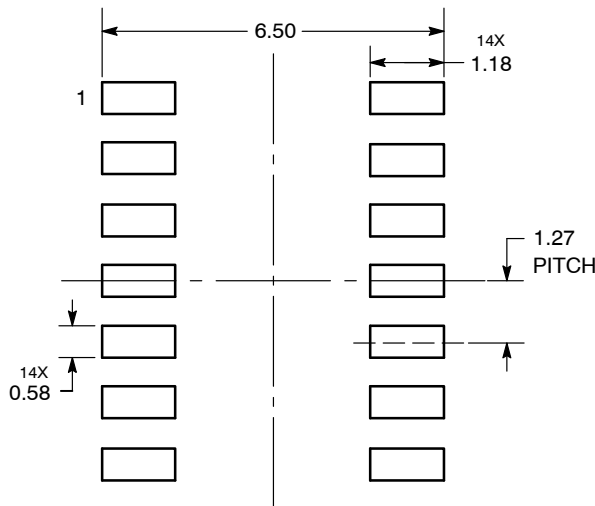
DATE 03 FEB 2016



- NOTES:
1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
 2. CONTROLLING DIMENSION: MILLIMETERS.
 3. DIMENSION b DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE PROTRUSION SHALL BE 0.13 TOTAL IN EXCESS OF AT MAXIMUM MATERIAL CONDITION.
 4. DIMENSIONS D AND E DO NOT INCLUDE MOLD PROTRUSIONS.
 5. MAXIMUM MOLD PROTRUSION 0.15 PER SIDE.

| DIM | MILLIMETERS | | INCHES | |
|-----|-------------|------|-----------|-------|
| | MIN | MAX | MIN | MAX |
| A | 1.35 | 1.75 | 0.054 | 0.068 |
| A1 | 0.10 | 0.25 | 0.004 | 0.010 |
| A3 | 0.19 | 0.25 | 0.008 | 0.010 |
| b | 0.35 | 0.49 | 0.014 | 0.019 |
| D | 8.55 | 8.75 | 0.337 | 0.344 |
| E | 3.80 | 4.00 | 0.150 | 0.157 |
| e | 1.27 BSC | | 0.050 BSC | |
| H | 5.80 | 6.20 | 0.228 | 0.244 |
| h | 0.25 | 0.50 | 0.010 | 0.019 |
| L | 0.40 | 1.25 | 0.016 | 0.049 |
| M | 0° | 7° | 0° | 7° |

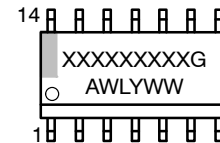
SOLDERING FOOTPRINT*



DIMENSIONS: MILLIMETERS

*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

GENERIC MARKING DIAGRAM*



- XXXXXX = Specific Device Code
- A = Assembly Location
- WL = Wafer Lot
- Y = Year
- WW = Work Week
- G = Pb-Free Package

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "▪", may or may not be present. Some products may not follow the Generic Marking.

STYLES ON PAGE 2

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SOIC-14
CASE 751A-03
ISSUE L

DATE 03 FEB 2016

STYLE 1:
 PIN 1. COMMON CATHODE
 2. ANODE/CATHODE
 3. ANODE/CATHODE
 4. NO CONNECTION
 5. ANODE/CATHODE
 6. NO CONNECTION
 7. ANODE/CATHODE
 8. ANODE/CATHODE
 9. ANODE/CATHODE
 10. NO CONNECTION
 11. ANODE/CATHODE
 12. ANODE/CATHODE
 13. NO CONNECTION
 14. COMMON ANODE

STYLE 2:
 CANCELLED

STYLE 3:
 PIN 1. NO CONNECTION
 2. ANODE
 3. ANODE
 4. NO CONNECTION
 5. ANODE
 6. NO CONNECTION
 7. ANODE
 8. ANODE
 9. ANODE
 10. NO CONNECTION
 11. ANODE
 12. ANODE
 13. NO CONNECTION
 14. COMMON CATHODE

STYLE 4:
 PIN 1. NO CONNECTION
 2. CATHODE
 3. CATHODE
 4. NO CONNECTION
 5. CATHODE
 6. NO CONNECTION
 7. CATHODE
 8. CATHODE
 9. CATHODE
 10. NO CONNECTION
 11. CATHODE
 12. CATHODE
 13. NO CONNECTION
 14. COMMON ANODE

STYLE 5:
 PIN 1. COMMON CATHODE
 2. ANODE/CATHODE
 3. ANODE/CATHODE
 4. ANODE/CATHODE
 5. ANODE/CATHODE
 6. NO CONNECTION
 7. COMMON ANODE
 8. COMMON CATHODE
 9. ANODE/CATHODE
 10. ANODE/CATHODE
 11. ANODE/CATHODE
 12. ANODE/CATHODE
 13. NO CONNECTION
 14. COMMON ANODE

STYLE 6:
 PIN 1. CATHODE
 2. CATHODE
 3. CATHODE
 4. CATHODE
 5. CATHODE
 6. CATHODE
 7. CATHODE
 8. ANODE
 9. ANODE
 10. ANODE
 11. ANODE
 12. ANODE
 13. ANODE
 14. ANODE

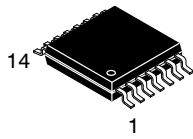
STYLE 7:
 PIN 1. ANODE/CATHODE
 2. COMMON ANODE
 3. COMMON CATHODE
 4. ANODE/CATHODE
 5. ANODE/CATHODE
 6. ANODE/CATHODE
 7. ANODE/CATHODE
 8. ANODE/CATHODE
 9. ANODE/CATHODE
 10. ANODE/CATHODE
 11. COMMON CATHODE
 12. COMMON ANODE
 13. ANODE/CATHODE
 14. ANODE/CATHODE

STYLE 8:
 PIN 1. COMMON CATHODE
 2. ANODE/CATHODE
 3. ANODE/CATHODE
 4. NO CONNECTION
 5. ANODE/CATHODE
 6. ANODE/CATHODE
 7. COMMON ANODE
 8. COMMON ANODE
 9. ANODE/CATHODE
 10. ANODE/CATHODE
 11. NO CONNECTION
 12. ANODE/CATHODE
 13. ANODE/CATHODE
 14. COMMON CATHODE

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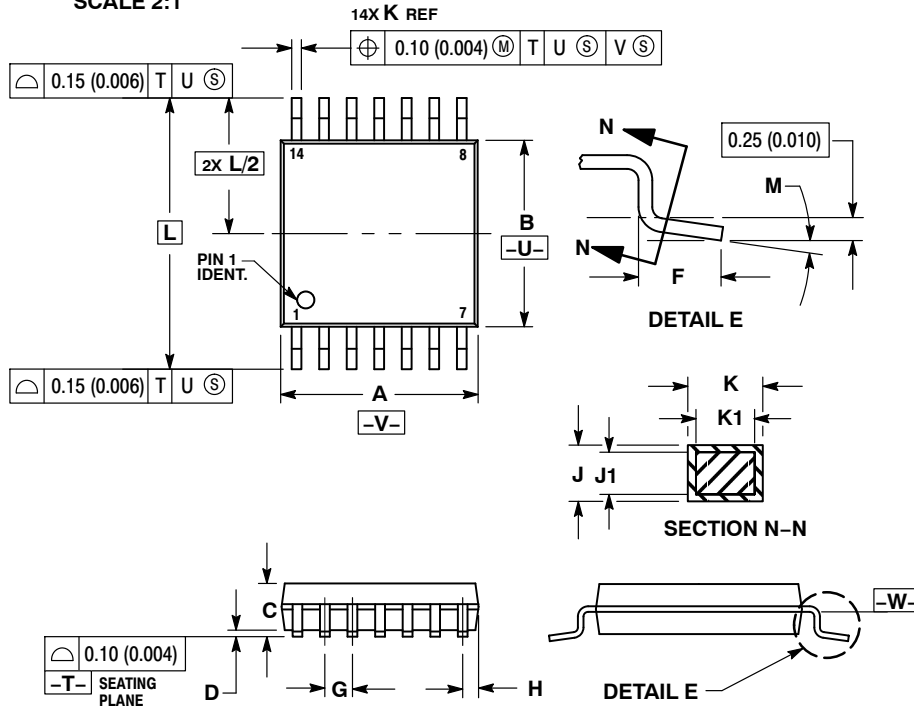
MECHANICAL CASE OUTLINE PACKAGE DIMENSIONS



TSSOP-14 WB
CASE 948G
ISSUE C

DATE 17 FEB 2016

SCALE 2:1

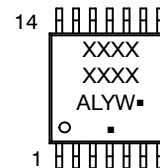


NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.
3. DIMENSION A DOES NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS. MOLD FLASH OR GATE BURRS SHALL NOT EXCEED 0.15 (0.006) PER SIDE.
4. DIMENSION B DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSION. INTERLEAD FLASH OR PROTRUSION SHALL NOT EXCEED 0.25 (0.010) PER SIDE.
5. DIMENSION K DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08 (0.003) TOTAL IN EXCESS OF THE K DIMENSION AT MAXIMUM MATERIAL CONDITION.
6. TERMINAL NUMBERS ARE SHOWN FOR REFERENCE ONLY.
7. DIMENSION A AND B ARE TO BE DETERMINED AT DATUM PLANE -W-.

| DIM | MILLIMETERS | | INCHES | |
|-----|-------------|------|-----------|-------|
| | MIN | MAX | MIN | MAX |
| A | 4.90 | 5.10 | 0.193 | 0.200 |
| B | 4.30 | 4.50 | 0.169 | 0.177 |
| C | --- | 1.20 | --- | 0.047 |
| D | 0.05 | 0.15 | 0.002 | 0.006 |
| F | 0.50 | 0.75 | 0.020 | 0.030 |
| G | 0.65 BSC | | 0.026 BSC | |
| H | 0.50 | 0.60 | 0.020 | 0.024 |
| J | 0.09 | 0.20 | 0.004 | 0.008 |
| J1 | 0.09 | 0.16 | 0.004 | 0.006 |
| K | 0.19 | 0.30 | 0.007 | 0.012 |
| K1 | 0.19 | 0.25 | 0.007 | 0.010 |
| L | 6.40 BSC | | 0.252 BSC | |
| M | 0° | 8° | 0° | 8° |

GENERIC MARKING DIAGRAM*

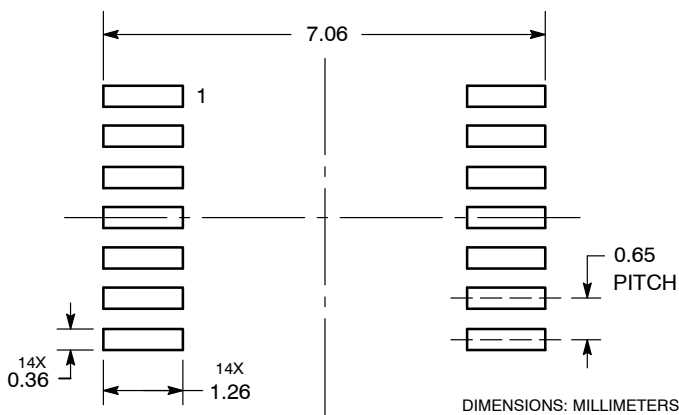


- A = Assembly Location
- L = Wafer Lot
- Y = Year
- W = Work Week
- = Pb-Free Package

(Note: Microdot may be in either location)

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "▪", may or may not be present. Some products may not follow the Generic Marking.

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Phone: 011 421 33 790 2910

Europe, Middle East and Africa Technical Support:

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For additional information, please contact your local Sales Representative